

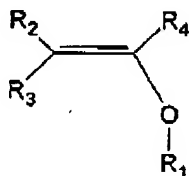
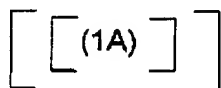
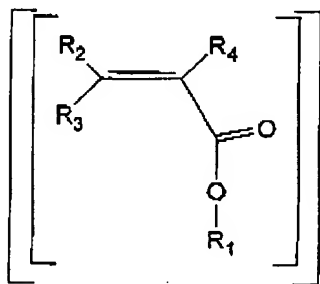
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 Filed: December 29, 2003

Amendments to the Claims:

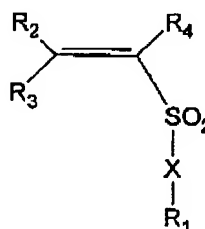
This listing of claims will replace all prior versions, and listings, of claims in the application:

1. (canceled)
2. (currently amended) ~~The A~~ photoresist composition comprising:
 - a) a polymer that is insoluble in an aqueous alkaline solution and comprises at least one acid labile group, and comprises at least one monomer unit having a pendant group selected from unsubstituted or substituted diamantane, triamantane or mixtures thereof; and
 - b) a compound capable of producing an acid upon irradiation, of claim 1

wherein the monomer unit is selected from



(1B)



(1C)

wherein

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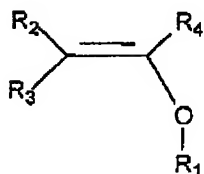
R_1 is $-Z$ or $-Y-Z$ where Y is a linear or branched alkylene or a monocyclic or polycyclic alkylene, Z is unsubstituted or substituted diamantane, triamantane or mixtures thereof; R_2 , R_3 , and R_4 are each independently selected from hydrogen, alkyl, alkoxyalkyl, cycloalkyl, cycloalkenyl, aryl, aralkyl, and CN or any two of R_2 , R_3 , and R_4 together with the carbon atoms to which they are attached form an unsubstituted or substituted mono- or polycycloalkenyl; X is O or NR_2 .

Claims 3 to 5 (canceled)

4. (canceled)

5. (canceled)

6. (currently amended) The photoresist composition of claim [[1]] 2 wherein the monomer unit is



(1B)

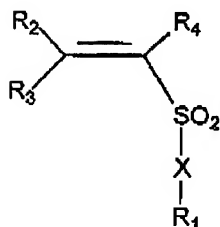
7. (canceled)

8. (previously presented) The photoresist composition of claim 6 wherein the diamantane and triamantane is substituted by one or more groups selected from hydroxy, hydroxyalkyl, alkyl, alkoxy, aryl, cycloalkyl, cycloalkyloxy, alkoxyalkyl,

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alkoxycycloalkyl, aryloxy, halogen, $-O-(CH_2)_n-COOtBu$, where n is 1 to 5, and where a carbon atom within the diamantane and triamantane is replaced by $A-(CH_2)_j-C(=O)-O-B$ where j is 0 to 5 and A and B represent direct bonds to adjacent carbon atoms to the replaced carbon atom.

9. (currently amended) The photoresist composition of claim [[1]] 2 wherein the monomer unit is



10. (canceled)

11. (previously presented) The photoresist composition of claim 9 wherein X is O .

12. (previously presented) The photoresist composition of claim 9 wherein X is NR_2 .

13. (previously presented) The photoresist composition of claim 9 wherein the diamantane and triamantane is substituted by one or more groups selected from hydroxy, hydroxyalkyl, alkyl, alkoxy, aryl, cycloalkyl, cycloalkyloxy, alkoxyalkyl, alkoxycycloalkyl, aryloxy, halogen, $-O-(CH_2)_n-COOtBu$, where n is 1 to 5; and where a carbon atom within the diamantane and triamantane is replaced by $A-(CH_2)_j-C(=O)-O-B$ where j is 0 to 5 and A and B represent direct bonds to adjacent carbon atoms to the replaced carbon atom.

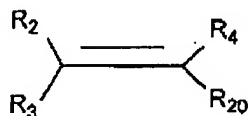
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14. (currently amended) The photoresist composition according to claim [[1]] 2, where the compound capable of producing an acid upon irradiation is a sulfonium or iodonium salt~~[[;]]~~.
15. (currently amended) The photoresist composition according to claim [[1]] 2, where the compound capable of producing an acid upon irradiation is selected from triphenylsulfonium nonafluorobutanesulfonate, diphenyliodonium trifluoromethanesulfonate, diphenyliodonium nonafluorobutanesulfonate, triphenylsulfonium trifluoromethanesulfonate, triazines, oxazoles, oxadiazoles, thiazoles, substituted 2-pyrones, phenol sulfonic esters, bis-sulfonylmethanes, bis-sulfonylmethanes and bis-sulfonyldiazomethanes.
16. (currently amended) A process of imaging a positive photoresist composition comprising the steps of:
- a) coating a substrate with a film of photoresist composition of claim [[1]] 2;
 - b) baking the substrate to substantially remove the solvent;
 - c) imagewise irradiating the photoresist film;
 - d) baking the photoresist film; and,
 - e) developing the irradiated photoresist film using an alkaline developer.
17. (original) The process according to claim 16, further comprising coating an antireflective film on the substrate prior to coating the photoresist.
18. (original) The process of claim 16, wherein the photoresist film is imagewise irradiated with light of wavelength in the range of 10nm to 300nm.

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19. (original) The process of claim 18, wherein the wavelength is selected from the following: 248 nm, 193 nm, 157 nm, 13.4 nm.
20. (original) The process of claim 18, where the imagewise irradiation is carried out with particle-type radiation.
21. (original) The process of claim 16, wherein the baking in step d) ranges from a temperature of from about 90°C to about 150°C for from about 30 seconds to about 180 seconds on a hot plate or from about 15 minutes to about 40 minutes in an oven.
22. (original) The process of claim 16, wherein the alkaline developer in step e) comprises an aqueous solution of tetramethyl ammonium hydroxide[[:]] .
23. (currently amended) The process of claim 16, in which the photoresist is subjected to a further heating step after step e)[[:]] .
24. (currently amended) The process of claim 16, in which the photoresist is subjected to a curing process after step e) comprising irradiating it with short wavelength or electron-beam radiation[[:]] .
25. (canceled)
26. (currently amended) A compound of the formula

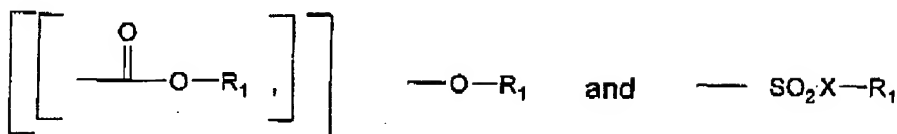
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(1)

wherein

R₂₀ is selected from



R₁ is —Z or —Y—Z where Y is a linear or branched alkylene or a monocyclic or polycyclic alkylene, Z is unsubstituted or substituted diamantane, triamantane or ~~and~~ mixtures thereof; R₂, R₃, and R₄ are each independently selected from hydrogen, alkyl, alkoxyalkyl, cycloalkyl, cycloalkenyl, aryl, aralkyl, and CN or any two of R₂, R₃, and R₄ together with the carbon atoms to which they are attached form an unsubstituted or substituted mono- or polycycloalkenyl; X is O or NR₂.

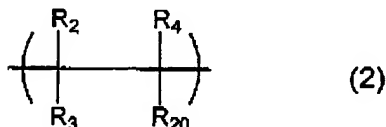
27. (canceled)

28. (original) The compound of claim 26 wherein R₂₀ is —O—R_1 .

29. (original) The compound of claim 26 wherein R₂₀ is $\text{—SO}_2\text{—X—R}_1$.

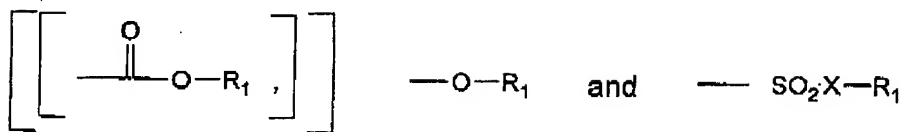
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30. (currently amended) A polymer comprising at least one repeating unit represented by formula (2)



wherein

R_{20} is selected from



R_1 is $-\text{Z}$ or $-\text{Y}-\text{Z}$ where Y is a linear or branched alkylene or a monocyclic or polycyclic alkylene, Z is unsubstituted or substituted diamantane, triamantane or ~~and~~ mixtures thereof; R_2 , R_3 , and R_4 are each independently selected from hydrogen, alkyl, alkoxyalkyl, cycloalkyl, cycloalkenyl, aryl, aralkyl, and CN or any two of R_2 , R_3 , and R_4 together with the carbon atoms to which they are attached form an unsubstituted or substituted mono- or polycycloalkenyl; X is O or NR_2 .

31. (canceled)

32. (original) The polymer of claim 30 The polymer of claim 30 wherein R_{20} is $-\text{O}-R_1$.

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33. (original) The polymer of claim 30 wherein R_{20} is $\text{---SO}_2\text{---X---R}_1$.
34. (previously presented) The compound of claim 26 wherein the diamantane and triamantane is substituted by one or more groups selected from hydroxy, hydroxyalkyl, alkyl, alkoxy, aryl, cycloalkyl, cycloalkyloxy, alkoxyalkyl, alkoxycycloalkyl, aryloxy, halogen, $\text{---O---(CH}_2\text{)}_n\text{---COOtBu}$, where n is 1 to 5, and where a carbon atom within the diamantane and triamantane is replaced by $\text{A---(CH}_2\text{)}_j\text{---C(=O)---O---B}$ where j is 0 to 5 and A and B represent direct bonds to adjacent carbon atoms to the replaced carbon atom.
35. (previously presented) The polymer of claim 30 wherein the diamantane and triamantane is substituted by one or more groups selected from hydroxy, hydroxyalkyl, alkyl, alkoxy, aryl, cycloalkyl, cycloalkyloxy, alkoxyalkyl, alkoxycycloalkyl, aryloxy, halogen, $\text{---O---(CH}_2\text{)}_n\text{---COOtBu}$, where n is 1 to 5, and where a carbon atom within the diamantane and triamantane is replaced by $\text{A---(CH}_2\text{)}_j\text{---C(=O)---O---B}$ where j is 0 to 5 and A and B represent direct bonds to adjacent carbon atoms to the replaced carbon atom.